

NPN power transistors

Features

■ NPN transistors

Applications

■ Audio, power linear and switching application

Description

The devices are manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The PNP types are BD236 and BD238 respectively.

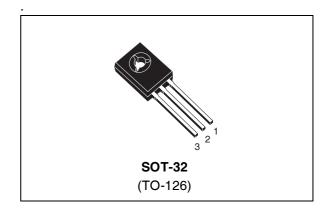


Figure 1. Internal schematic diagram

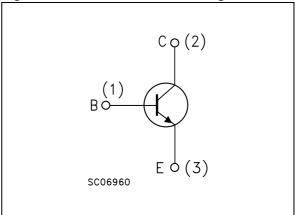


Table 1. Device summary

Order code	Marking	Package	Packaging
BD235	BD235	SOT-32	Tube
BD237	BD237	SOT-32	Tube

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		BD235	BD237	
V _{CBO}	Collector-base voltage (I _E = 0)	60	100	V
V _{CER}	Collector-emitter voltage (R _{BE} = 1KΩ)	60	100	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	60	80	V
V _{EBO}	Emitter-base voltage (I _C = 0)	5		V
I _C	Collector current	2		Α
I _{CM}	Collector peak current (t _p < ms)	6		Α
P _{TOT}	Total dissipation at T _{case} = 25°C	25		W
T _{stg}	Storage temperature	-65 to 150		°C
TJ	Max. operating junction temperature	150		°C

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C; unless otherwise specified)$

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V_{CB} = rated V_{CBO} V_{CB} = rated V_{CBO} T_{C} = 150°C			0.1 2	mA mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5V			1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 100mA for BD235 for BD237	60 80			V V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 1A			0.6	V
V _{BE} ⁽¹⁾	Base-emitter voltage	I _C = 1A			1.3	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 150$ mA $V_{CE} = 2V$ $I_C = 1$ A $V_{CE} = 2V$	40 25			

^{1.} Pulsed duration = 300 ms, duty cycle ≥1.5%.

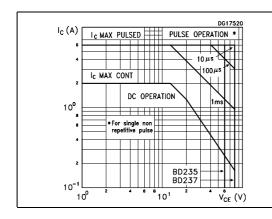
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Electrical characteristics BD235 BD237

2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

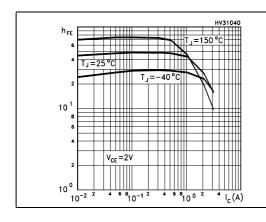
Figure 3. Derating curves



P_{tot} (%)
100
100
1s/B
50
0 50 100 T_C (°C)

Figure 4. DC current gain

Figure 5. DC current gain



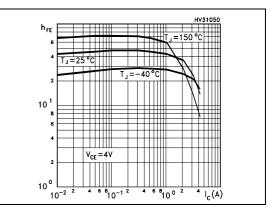
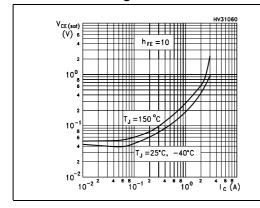
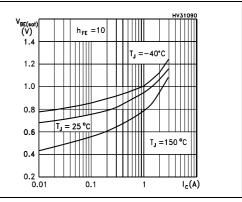


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage





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Figure 8. Base-emitter on voltage

Figure 9. Resistive load switching time

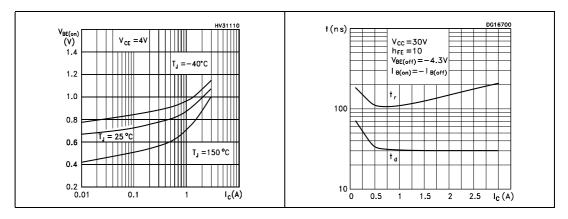
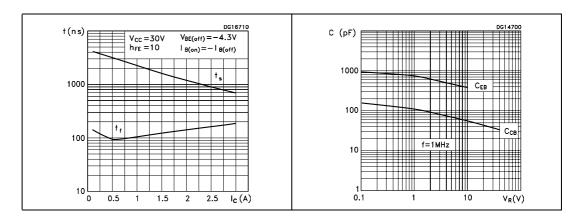
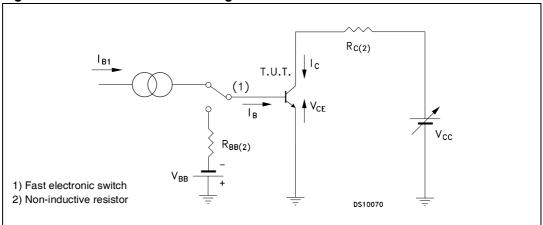


Figure 10. Resistive load switching time Figure 11. Capacitance curves



2.2 Test circuit

Figure 12. Resistive load switching test circuit



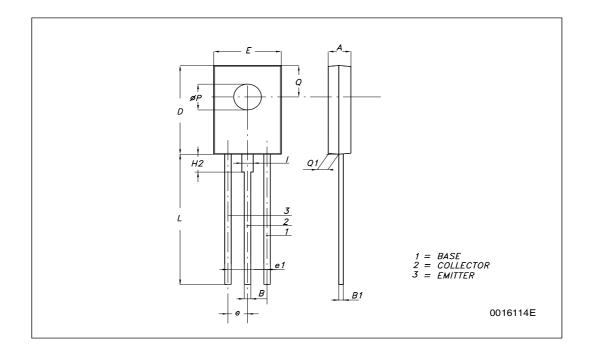
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



SOT-32 (TO-126) mechanical data

DIM	mm.		
DIM.	MIN.	ТҮР	MAX.
Α	2.4		2.9
В	0.64		0.88
B1	0.39		0.63
D	10.5		11.05
E	7.4		7.8
е	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.3		16
Р	2.9		3.2
Q		3.8	
Q1	1		1.52
H2		2.15	
ı		1.27	



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Revision history BD235 BD237

4 Revision history

Table 4. Revision history

Date	Revision	Changes
11-Feb-2003	1	Initial Release
09-Jul-2007	2	Figures: 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 and figure 12 have been added.

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